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Latest Results on Radiation Tolerance of Diamond Detectors & Status of 3D Diamond

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on behalf of the RD42 Collaboration

RD42:

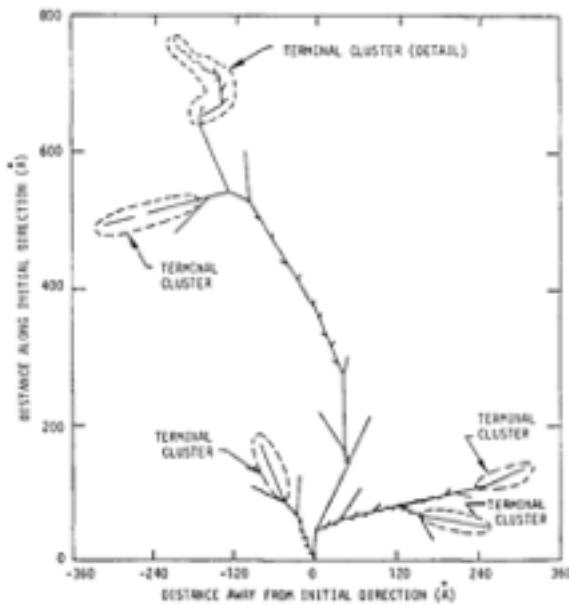
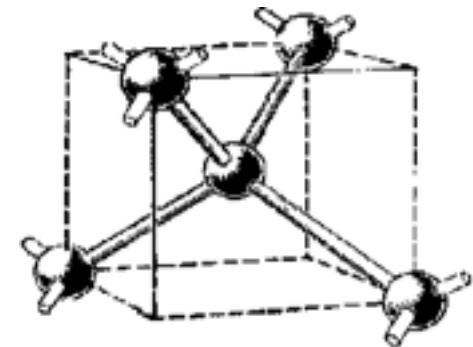
123 participants, 30 institutes

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Diamond properties

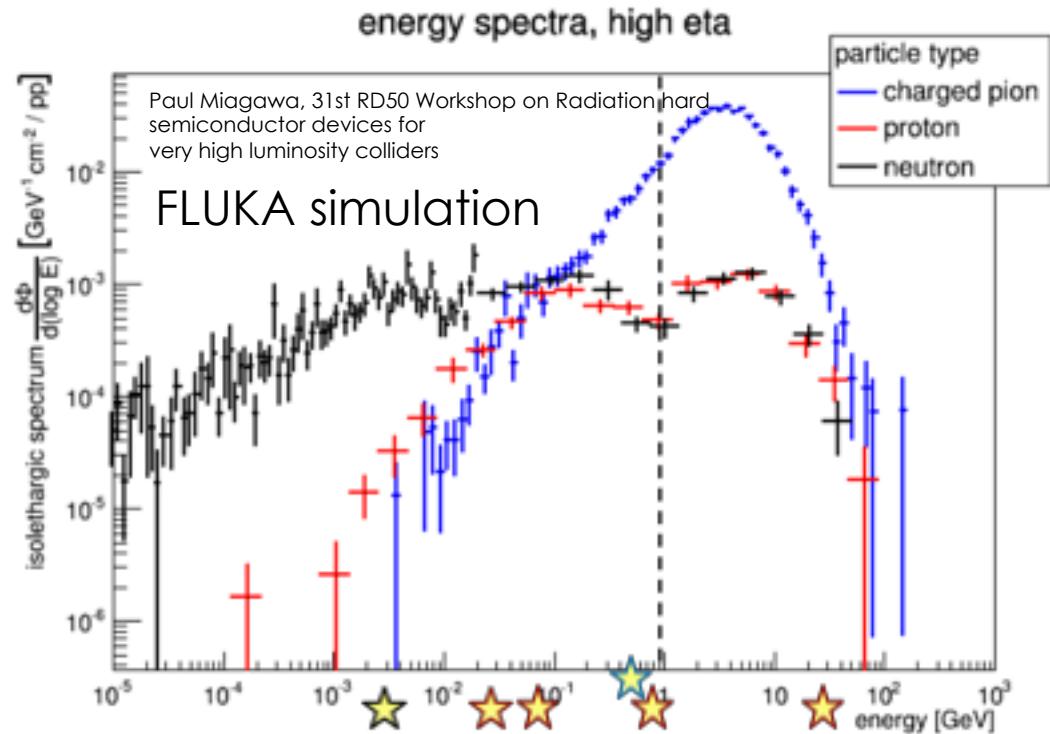
Property	Diamond	Silicon
band gap [eV]	5.47	1.12
resistivity [Ωcm]	$>10^{11}$	2.3e5
ionisation density MIP [eh/mm]	36	89
displacement energy [eV]	43	25



- Radiation produces cluster and point defects.
- Displacement energy per atom higher in Diamond compared to Silicon.
- Naive extrapolation:
Diamond should be more radiation tolerant than Silicon.

Tests of Radiation Tolerance

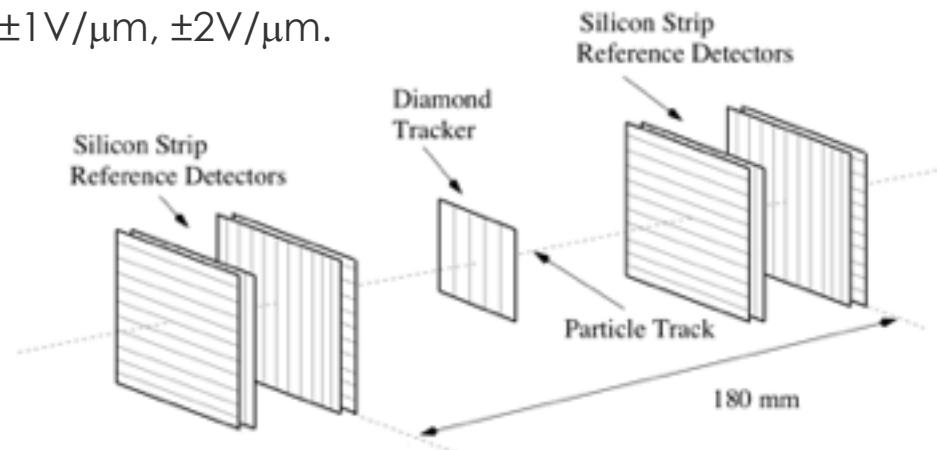
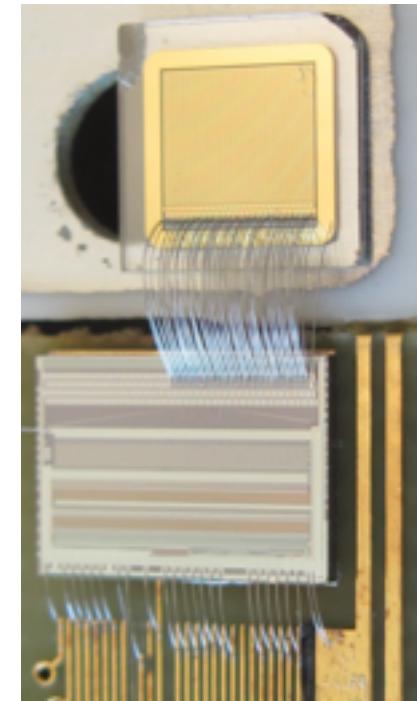
- Irradiate with **proton, pions** and **neutrons**.
 - Energies within the expected radiation profile at HL-LHC.
 - HL-LHC fluence requirement about 2×10^{16} neq.



	Proton 	Pion 	Neutron 
Energy	25MeV – 24GeV	300 MeV	1-10 MeV
Fluence	1.27×10^{16} p cm $^{-2}$	6×10^{14} π cm $^{-2}$	1.3×10^{16} n cm $^{-2}$

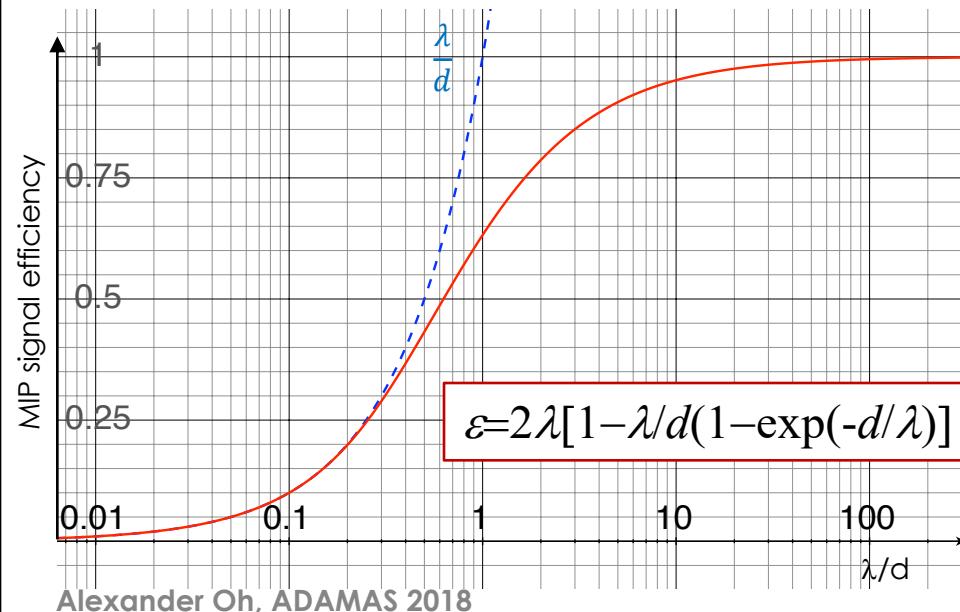
Radiation Tolerance: Characterization

- **Irradiated sensors are metallized with strip pattern.**
 - Pitch 50um, size typically 5x5mm² or 10x10mm².
 - Strips wire bonded to multi-channel low noise charge integrating amplifier (VA2 readout, noise ~ 80e).
 - Before test sensors are exposed to ⁹⁰Sr beta particles to fill charge traps.
- **Signal response tested with MIPs.**
 - **120 GeV/c protons** from CERN SPS, H6 beam line.
 - Beam telescope predicts track position to ~4μm.
 - Diamond detector electric field $E = \pm 1\text{V}/\mu\text{m}, \pm 2\text{V}/\mu\text{m}$.
 - Require single track on active area, no threshold on strip signals.
 - Build signal of highest two strip cluster within 10 strips around the track.



Radiation Tolerance: Characterization

- MIP signal is measured, expressed in charge collection distance defined as $d[\mu\text{m}] = Q_m[\text{e}] / 36 [\text{e}/\mu\text{m}]$
- Traps reduce the life-time of charge carriers, or “Schubweg” (λ).
 - Relation between MIP signal efficiency ε and λ :



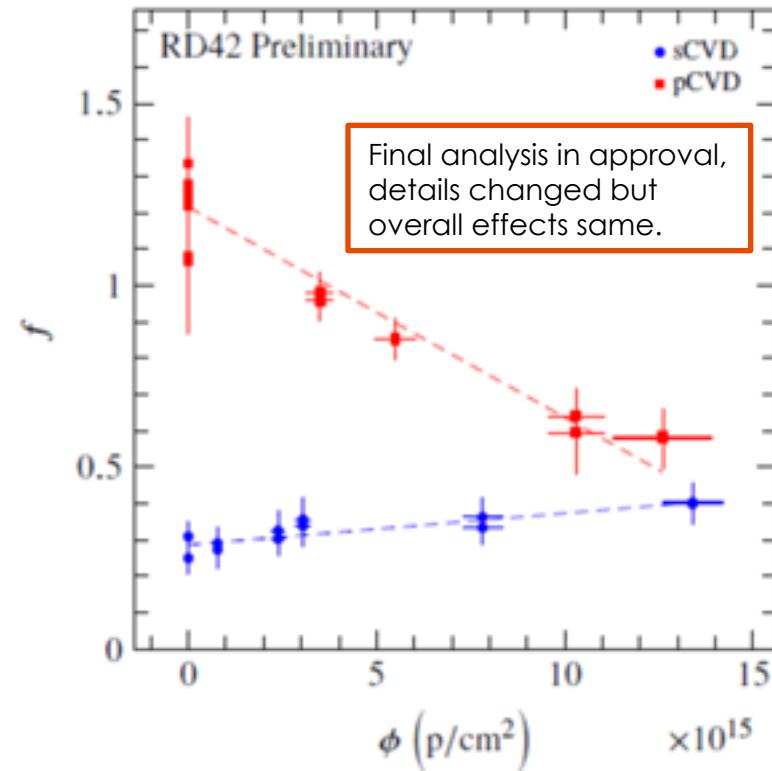
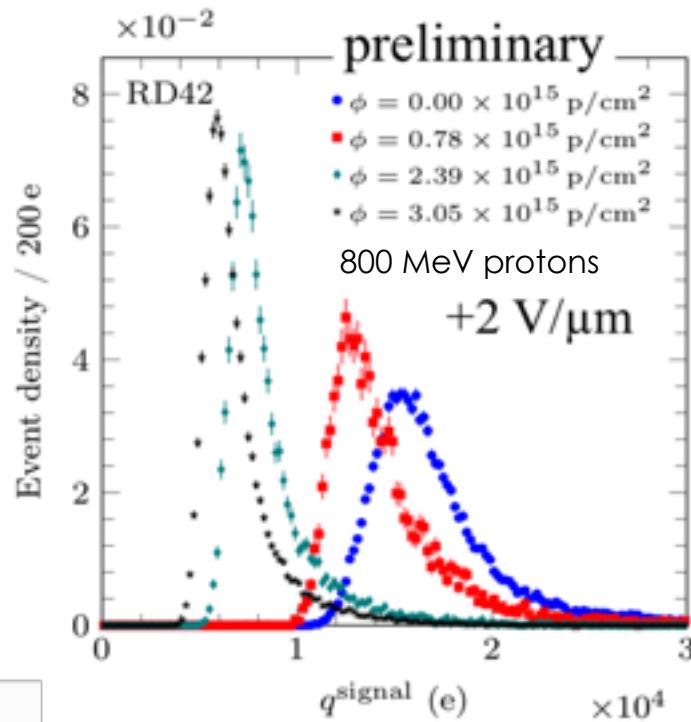
Radiation damage constant is fitted with simple model:

$$\frac{1}{\lambda} = \frac{1}{\lambda_0} + k_\lambda \Phi$$

damage constant
particle flux

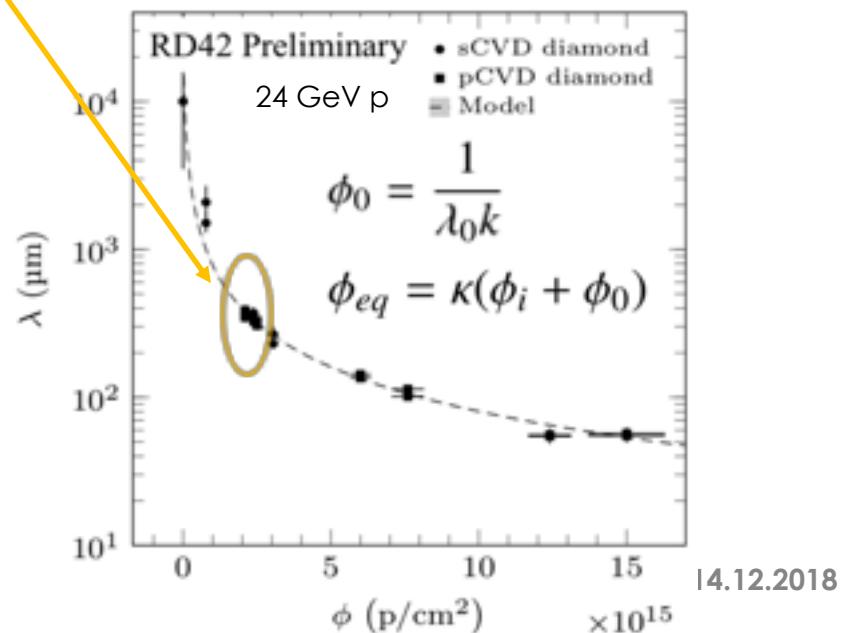
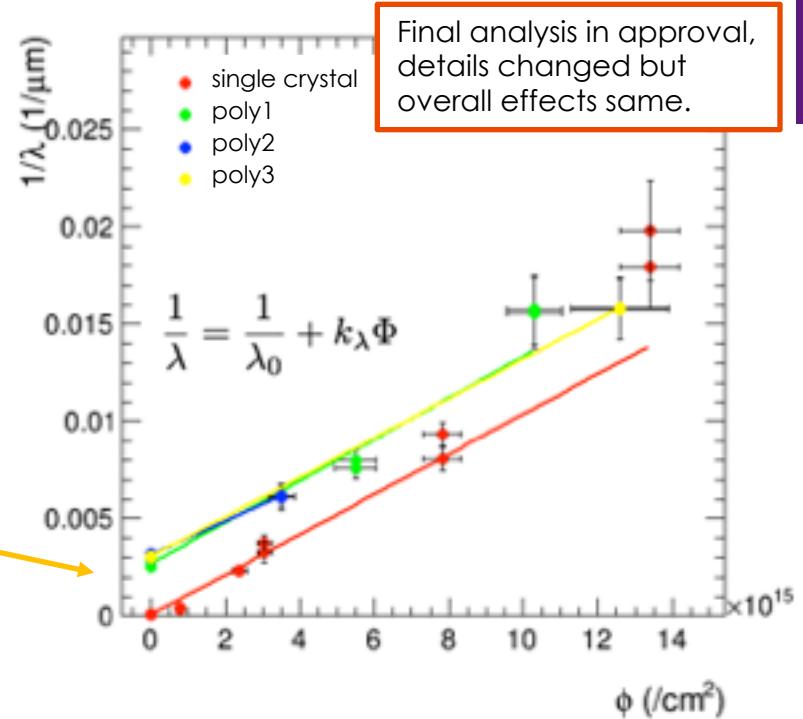
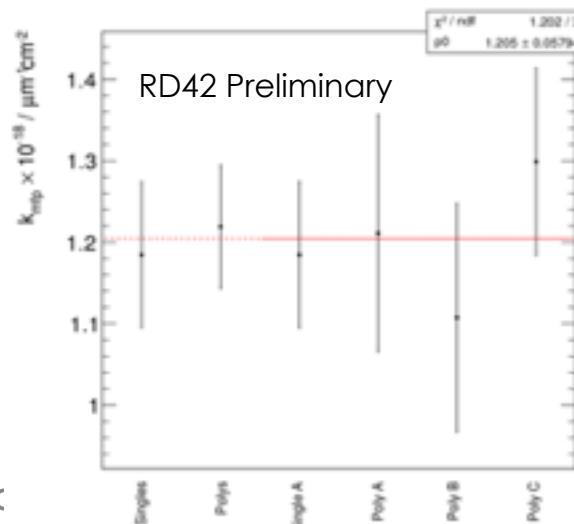
Radiation Tolerance: Characterization

- Typical Landau Spectra after irradiation of pCVD.
- For pCVD see reduction of **FWHM / MP** with irradiation.
 - Expected from polycrystalline nature of material!
 - Single crystal material almost flat.



Radiation Tolerance: Characterization

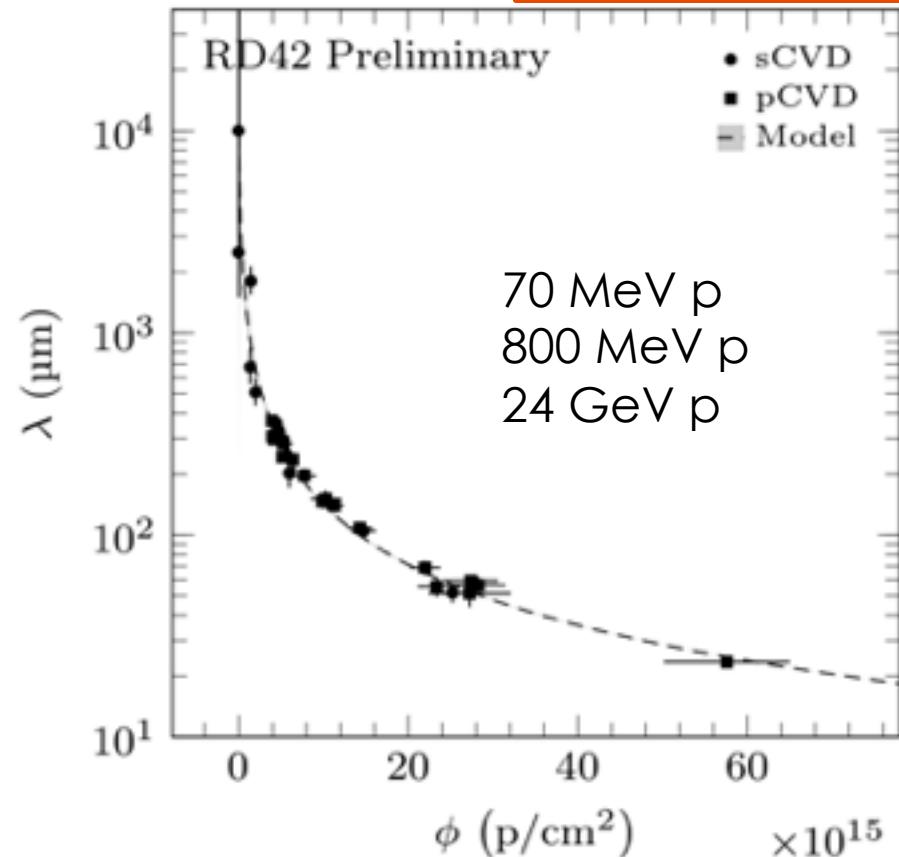
- Damage factor k is determined for each sample.
- **pCVD** diamonds are offset by λ_0 to account for initial finite carrier lifetime.
- Final damage factor averaged over all samples.



Radiation Tolerance

■ 24 GeV protons

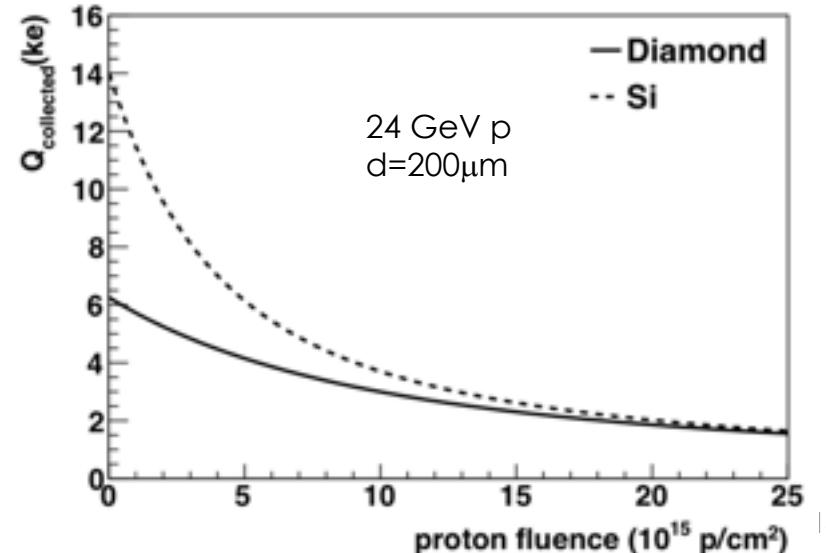
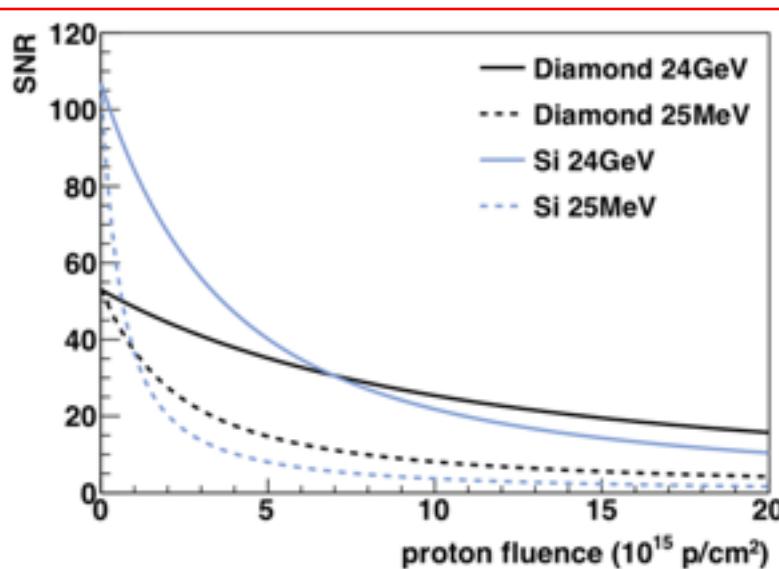
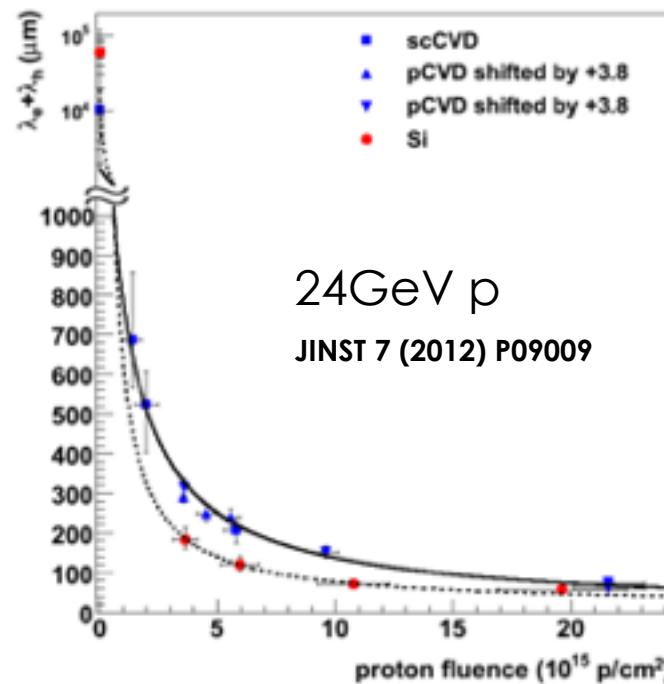
- $k_\lambda = 0.67 \pm 0.04 \times 10^{-18} \text{ cm}^2 \mu\text{m}^{-1}$
- polycrystalline diamond sample offset by $\Phi \sim 5 \times 10^{15}$ to account for existing traps.
- Poly and single crystal diamond show consistent damage constants.



L. Baeni ETHZ Thesis
<https://www.research-collection.ethz.ch/handle/20.500.11850/222412>

Radiation Tolerance: Comparison to Si

- k factors typically 2-3 times higher for Silicon.
- A comparison to Si needs to take into account:
 - leakage current
 - capacitance
- Possible figure of merit
Signal to noise ratio:

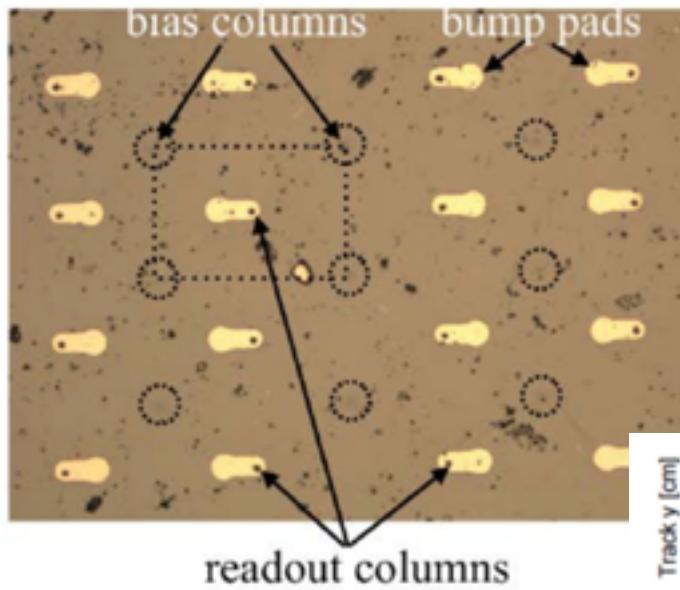


RD42: 3D diamond pixel tests in 2017/18

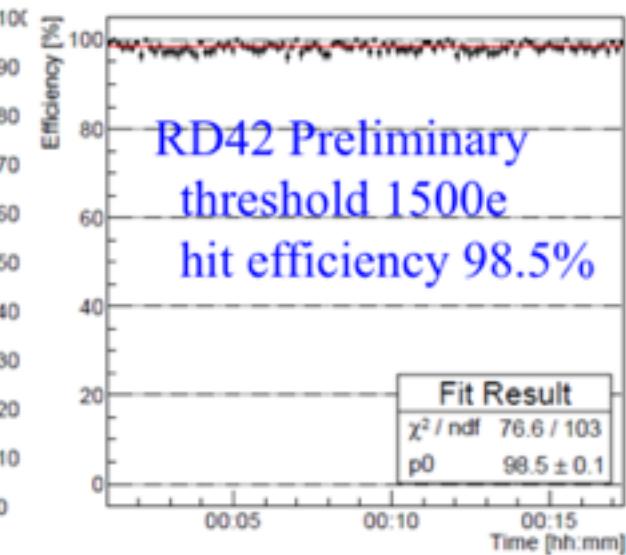
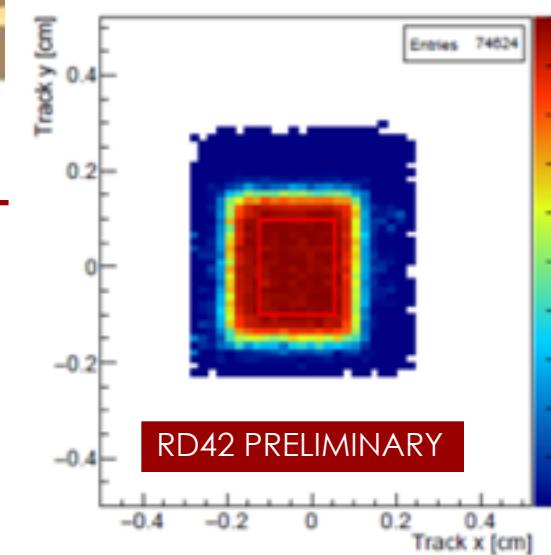
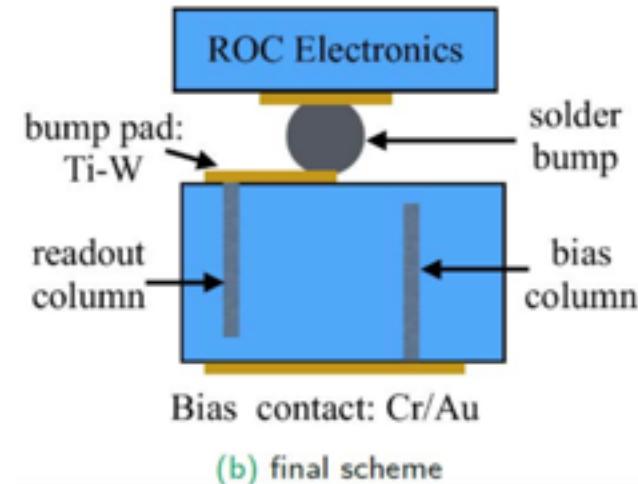
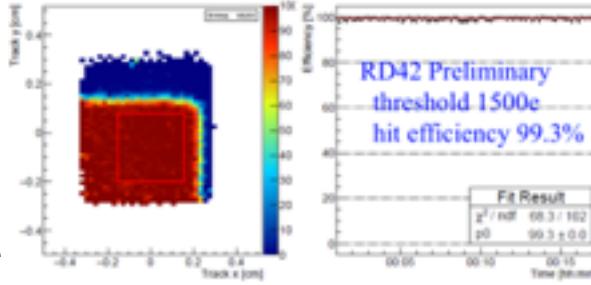
- 100x150 μm^2 basic cell
- 100x125 μm^2 basic cell + 115x133 μm^2 basic hex cell
- 50x50 μm^2 basic cell, 2x3 ganging (100x150 μm^2)
- 50x50 μm^2 basic cell, 1x5 ganging (50x250 μm^2)
- All detectors bump bonded to pixel read-out chip.
- Analysis work is in full swing, some preliminary plots in the next slides.

RD42: 3D diamond pixel tests in 2017/18

- 100x150 μm^2 basic cell

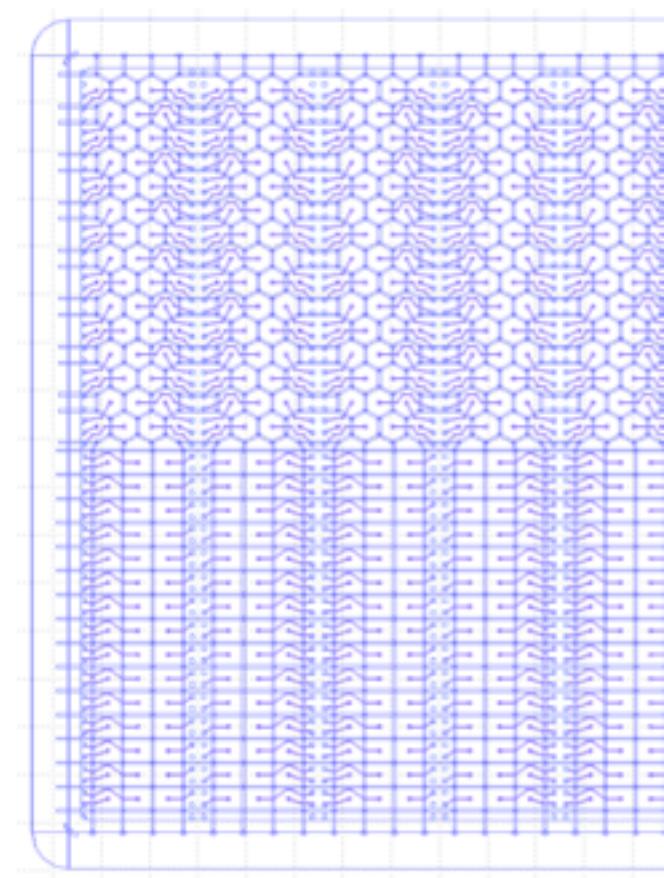
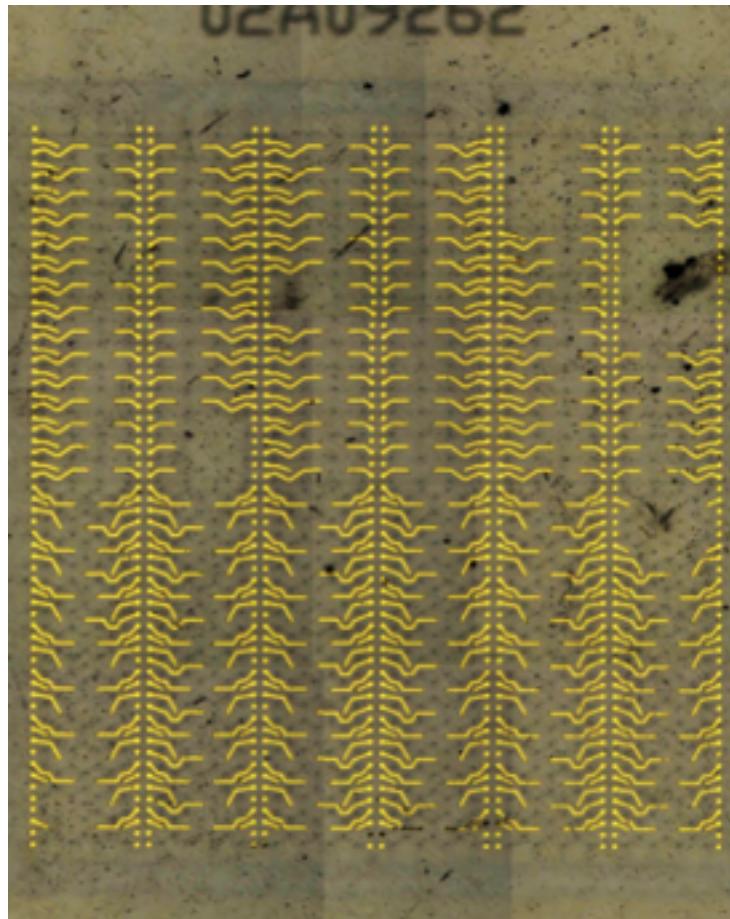
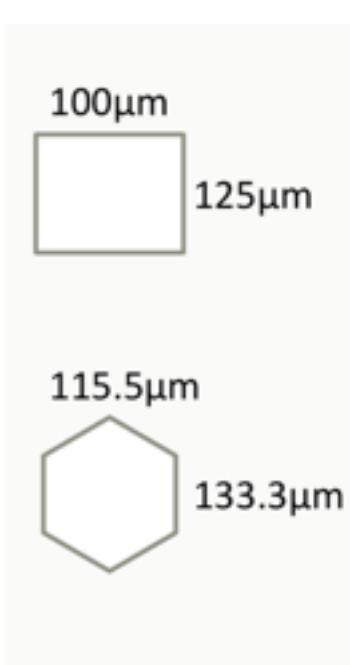


Silicon reference



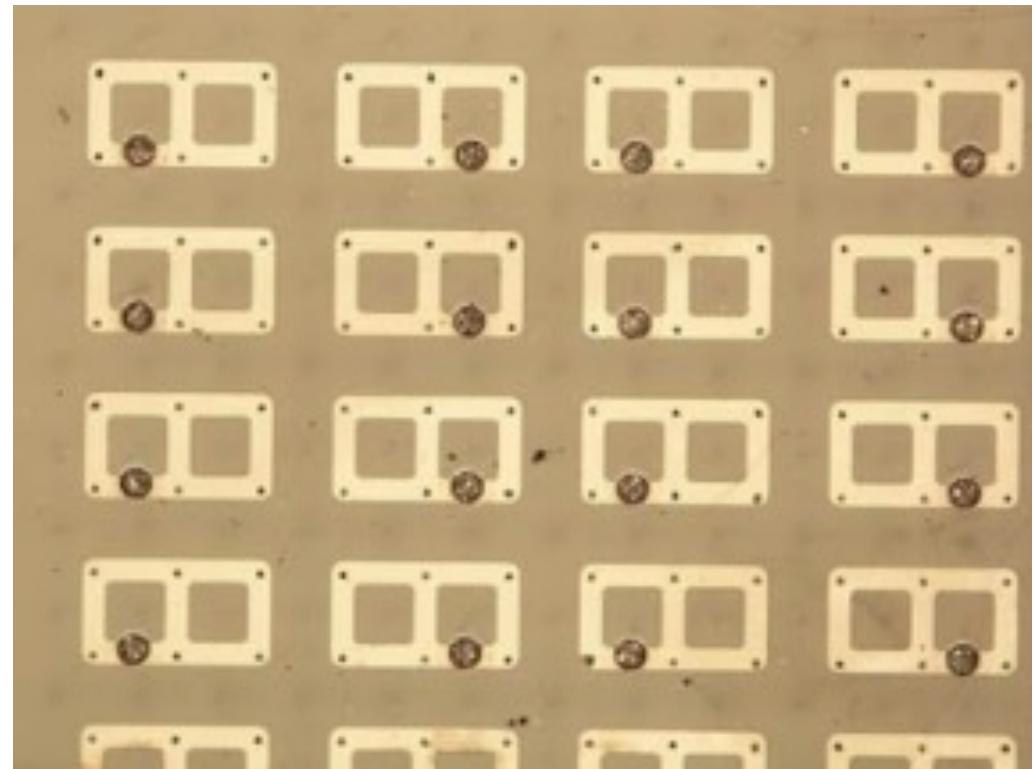
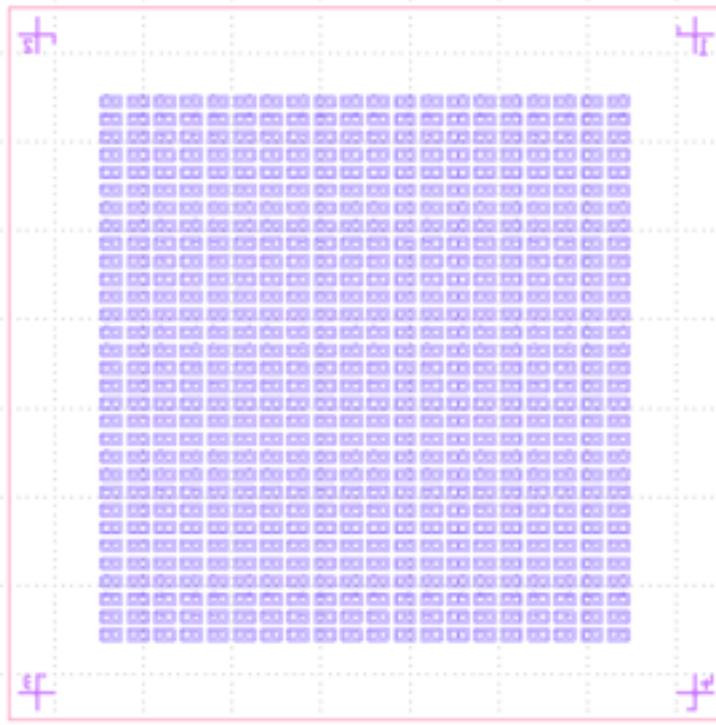
RD42: 3D diamond pixel tests in 2017/18

- 100x125 μm^2 basic cell + 115x133 μm^2 basic hex cell



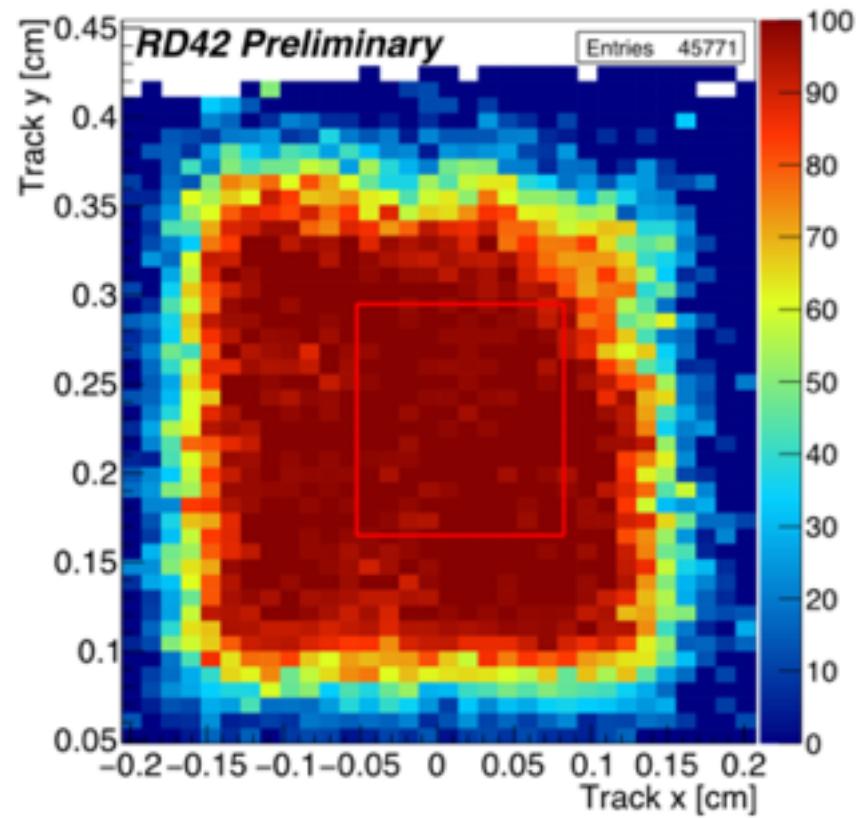
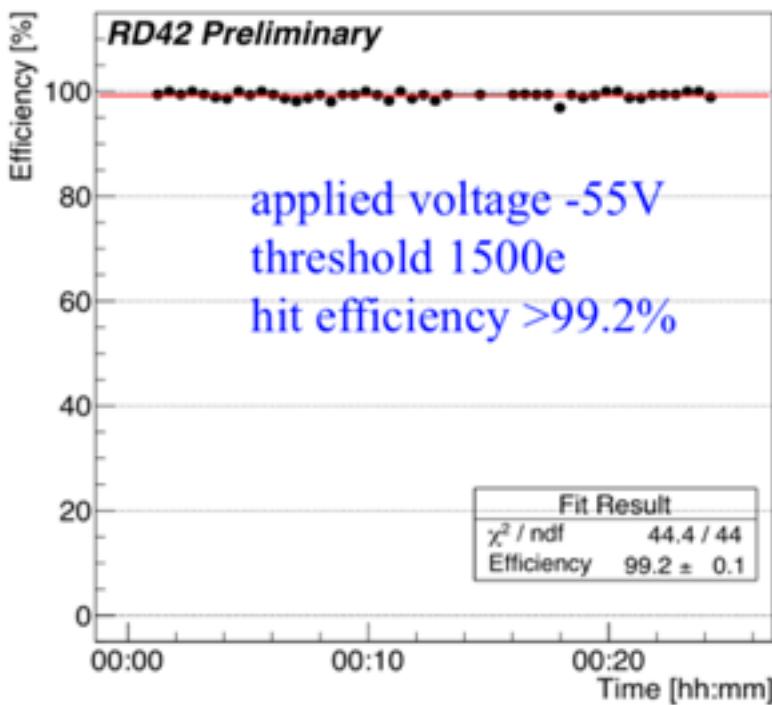
RD42: 3D diamond pixel tests in 2017/18

- 50x50 μm^2 basic cell, 2x3 ganging (100x150 μm^2)



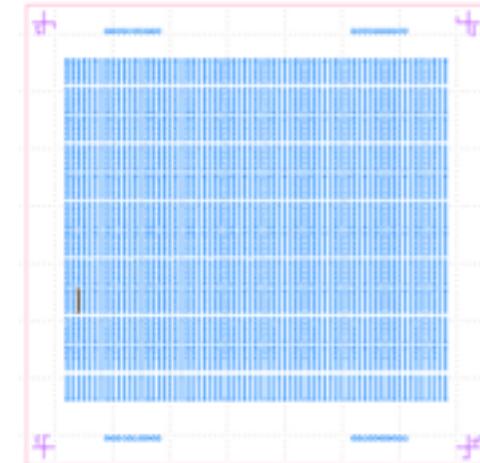
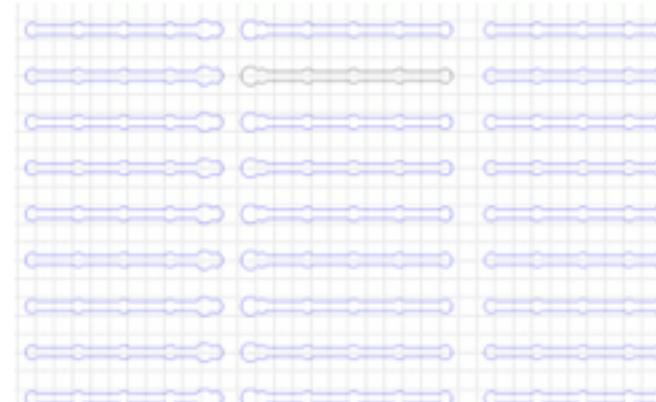
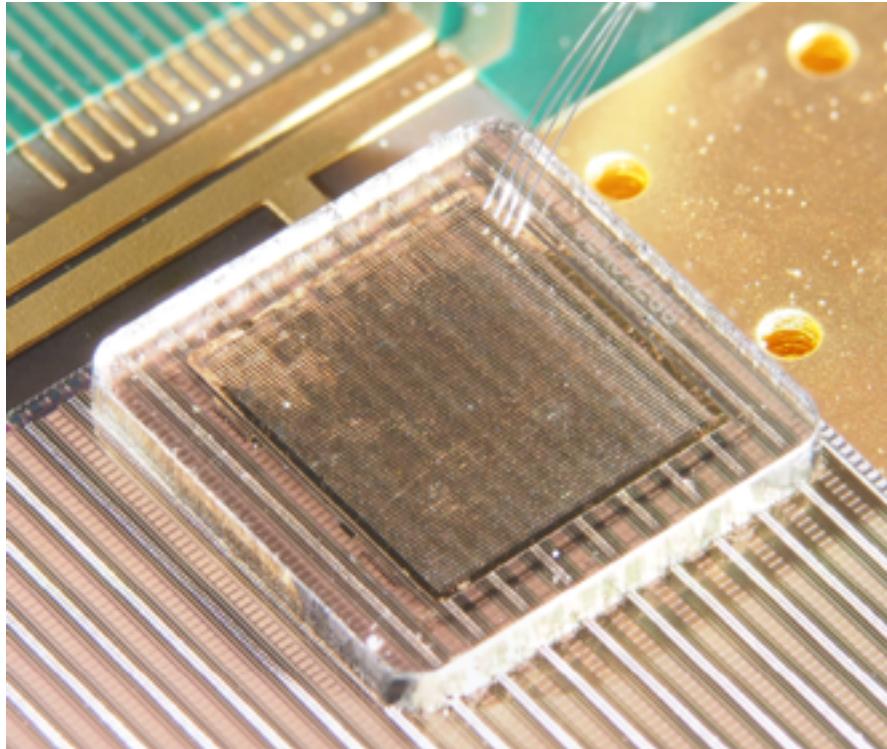
RD42: 3D diamond pixel tests in 2017/18

- 50x50 μm^2 basic cell, 2x3 ganging (100x150 μm^2)



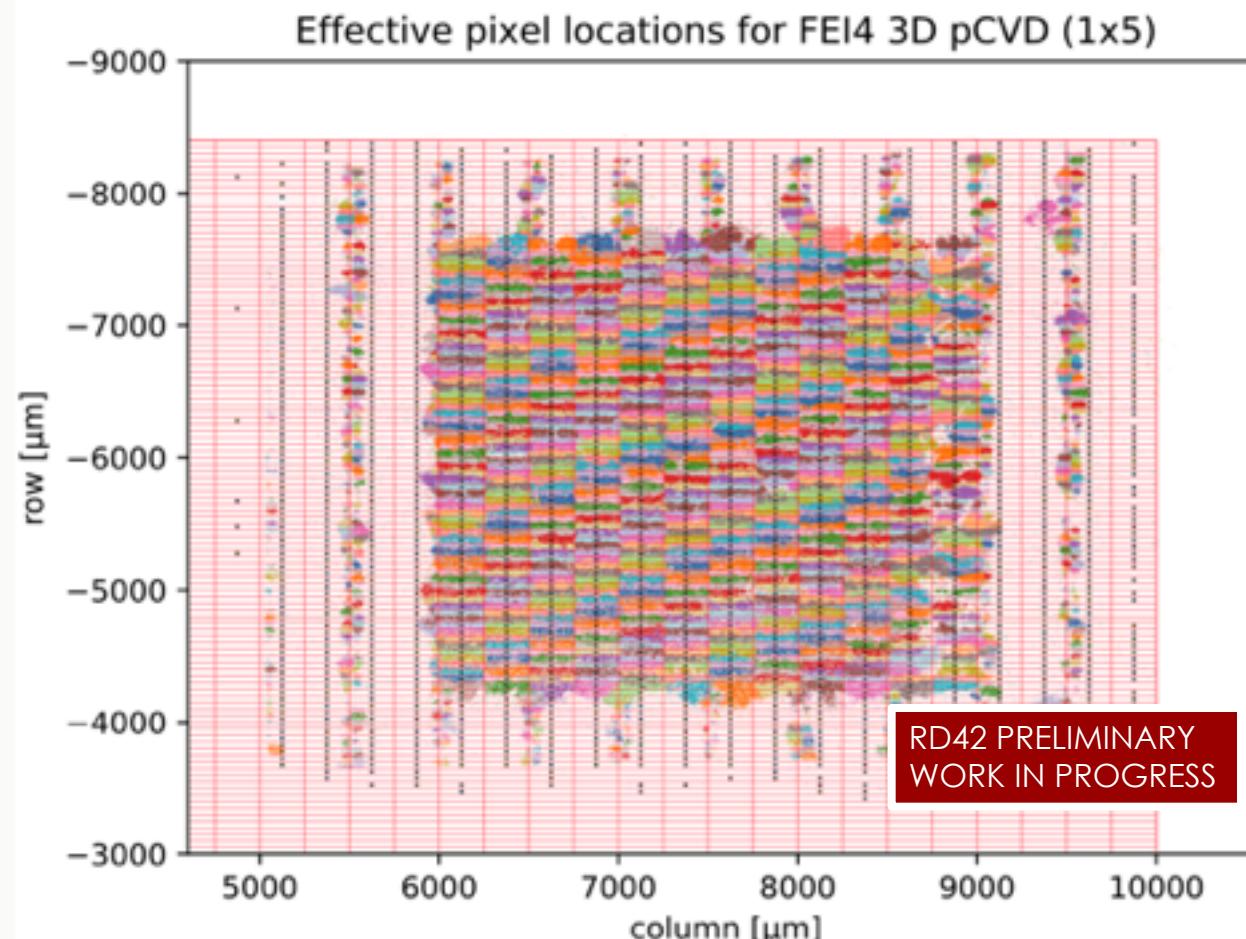
RD42: 3D diamond pixel tests in 2017/18

- 50x50 μm^2 basic cell, 1x5 ganging (50x250 μm^2)



RD42: 3D diamond pixel tests in 2017/18

- 50x50 μm^2 basic cell, 1x5 ganging (50x250 μm^2)



Summary & Outlook

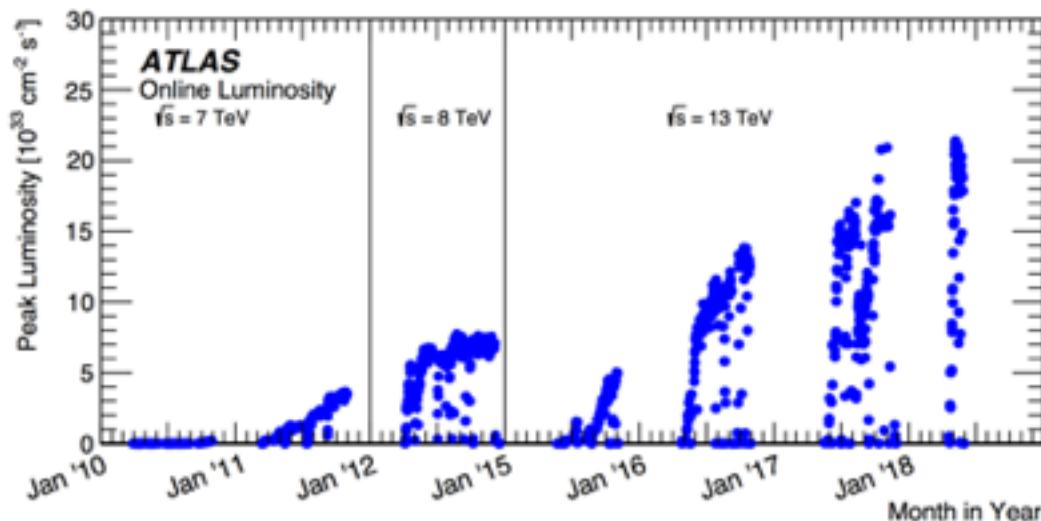
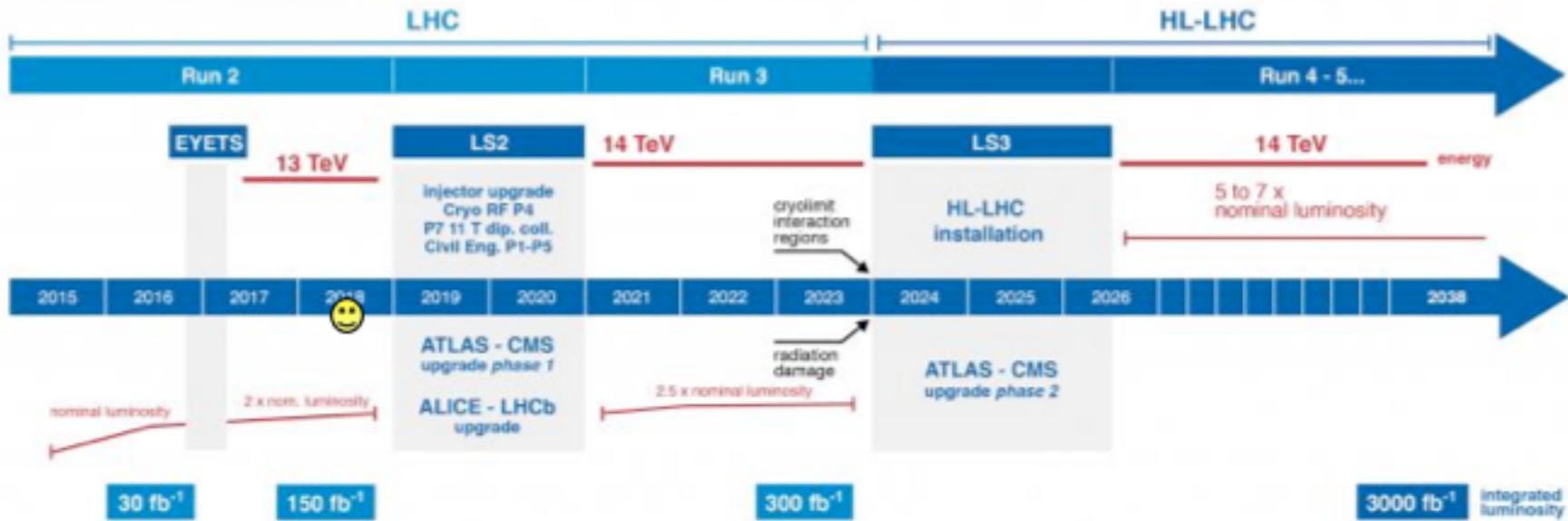
- Radiation tolerance has been studied with protons, pions and neutrons.
 - Paper ready very soon!
- 3D detector prototype with $50 \times 50 \mu\text{m}^2$ basic cell size tested with beams.
 - Analysis still ongoing, sneak preview shows promising results.
- For 2019:
 - Investigate irradiated 3D detectors.
 - Prototype for Beam Conditions Monitor for HL-LHC.

Acknowledgements

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BACKUP

Challenges Ahead



- Luminosity (L) upgrades of the LHC:
instantaneous L by **factor ~ 3** ,
integrated L by **factor ~ 10** .
- Luminosity \sim Radiation damage.
- Need new technologies in the innermost layers to survive the radiation levels.